

36 V, 0.8% Accuracy, 300 mA, Voltage Regulator for Automotive Applications

NO.EC-321-240724

OUTLINE

The R1513S is a CMOS-based voltage regulator (VR) that specifically designed for automotive applications featuring 300 mA output current and 36 V input voltage. Internally, the R1513S consists of a fold-back protection circuit, a short current protection circuit and a thermal shutdown circuit in addition to the basic regulator circuit. The performance is specified for 25°C with $\pm 0.8\%$ output voltage accuracy and for the -40°C to 125°C temperature range with $\pm 1.0\%$ output voltage accuracy. The operating temperature range is -40°C to 125°C and the maximum input voltage is 36 V. All these features make the R1513S ideal for power source for car accessories and electronic control units in automotive vehicles.

The R1513S is available in 1.2 V, 1.5 V, 1.8 V, 3.3 V, 3.4 V, 4.0 V and 5.0 V fixed output voltage options. By using external divider resistors, the output voltage can be set over a 1.2 V to 18.0 V range.

The R1513S is offered in a 6-pin HSOP-6J high wattage package.

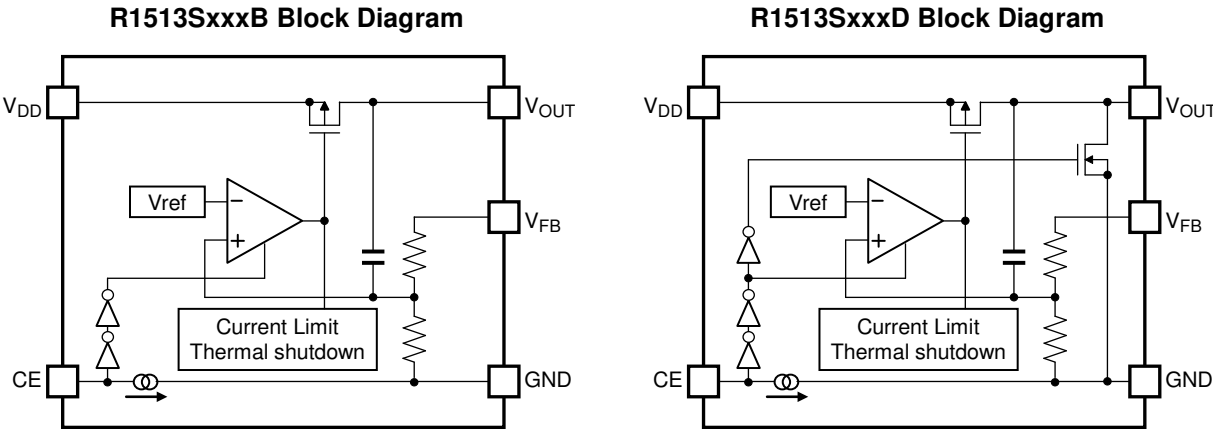
FEATURES

- Input Voltage (Maximum Ratings) 3.5 V to 36 V (50 V)
- Operating Temperature Range -40°C to 125°C
- Supply Current Typ. 75 μA
- Standby Current Typ. 0.1 μA
- Dropout Voltage Typ. 0.32 V ($I_{\text{OUT}} = 300 \text{ mA}$, $V_{\text{OUT}} = 5.0 \text{ V}$)
- Output Voltage Accuracy $\pm 0.8\%$ ($T_a = 25^{\circ}\text{C}$)
 $\pm 1.0\%$ (-40°C to 125°C)
- Line Regulation Typ. 0.01%/V ($V_{\text{DD}} = V_{\text{OUT}} + 1 \text{ V}$ to 36 V)
- Package Type HSOP-6J
- Output Voltage 1.2 V / 1.5 V / 1.8 V / 3.3 V / 3.4 V / 4.0 V / 5.0 V
- Short-current Protection Circuit Current Limit Typ. 50 mA
- Fold-back Protection Circuit Current Limit Typ. 450 mA
- Thermal Shutdown Circuit Shutdown at Typ. 160°C
- Ripple Rejection Typ. 70 dB ($f = 100 \text{ Hz}$)
- Ceramic Capacitor Compatible C1 = 1.0 μF or more, C2 = 4.7 μF or more

APPLICATIONS

- Power source for car accessories including car audio equipment, car navigation system, and ETC system.
- Power source for control units including EV inverter and charge control.

BLOCK DIAGRAM



SELECTION GUIDE

The set output voltage and the auto-discharge option^{*1} are user-selectable options.

Selection Guide

Product Name	Package	Quantity per Reel	Pb Free	Halogen Free
R1513Sxx1*-E2-#E	HSOP-6J	1,000 pcs	Yes	Yes

xx: Specify the set output voltage (V_{SET}) from below.

1.2 V (12) / 1.5 V (15) / 1.8 V (18) / 3.3 V (33) / 3.4 V (34) / 4.0 V (40) / 5.0 V (50)

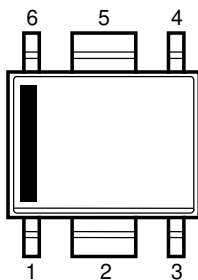
*: Specify the auto-discharge option.
B: Auto-discharge option not included
D: Auto-discharge option included

#: Specify the automotive class code.

	Operating Temperature Range	Guaranteed Specs Temperature Range	Screening
A	-40°C to 125°C	25°C	High Temperature
K	-40°C to 125°C	-40°C to 125°C	High and Low Temperature

^{*1} Auto-discharge function quickly lowers the output voltage to 0 V, when the chip enable signal is switched from the active mode to the standby mode, by releasing the electrical charge accumulated in the external capacitor.

PIN DESCRIPTION



HSOP-6J Pin Configuration

HSOP-6J Pin Description

Pin No.	Symbol	Description
1	V_{OUT}	Output Pin
2	GND ^{*1}	Ground Pin
3	V_{FB}	Feedback Pin
4	CE	Chip Enable Pin, Active-high
5	GND ^{*1}	Ground Pin
6	V_{DD}	Input Pin

^{*1} The GND pins must be wired together when they are mounted on board.

ABSOLUTE MAXIMUM RATINGS

Absolute Maximum Ratings

Symbol	Item		Rating	Unit
V_{IN}	Input Voltage		-0.3 to 50	V
V_{IN}	Peak Input Voltage ^{*1}		60	V
V_{CE}	CE Pin Input Voltage		-0.3 to 50	V
V_{FB}	V_{FB} Pin Input Voltage		-0.3 to $V_{OUT} + 0.3 \leq 50$	V
V_{OUT}	Output Voltage		-0.3 to $V_{IN} + 0.3 \leq 50$	V
P_D	Power Dissipation ^{*2}	Ultra High Wattage Land Pattern	3400	mW
		Standard Land Pattern	2100	
T_j	Junction Temperature		-40 to 150	°C
T_{stg}	Storage Temperature Range		-55 to 150	°C

^{*1} Duration time = 200 ms

^{*2} Refer to *PACKAGE INFORMATION* for detailed informatoin.

ABSOLUTE MAXIMUM RATINGS

Electronic and mechanical stress momentarily exceeded absolute maximum ratings may cause permanent damage and may degrade the life time and safety for both device and system using the device in the field. The functional operation at or over these absolute maximum ratings is not assured.

RECOMMENDED OPERATING CONDITIONS

Recommended Operating Conditions

Symbol	Item	Rating	Unit
V_{IN}	Input Voltage	3.5 to 36	V
T_a	Operating Temperature Range	-40 to 125	°C

RECOMMENDED OPERATING CONDITIONS

All of electronic equipment should be designed that the mounted semiconductor devices operate within the recommended operating conditions. The semiconductor devices cannot operate normally over the recommended operating conditions, even if they are used over such conditions by momentary electronic noise or surge. And the semiconductor devices may receive serious damage when they continue to operate over the recommended operating conditions.

ELECTRICAL CHARACTERISTICS

$C1 = 1.0 \mu\text{F}$, $C2 = 4.7 \mu\text{F}$, $V_{\text{OUT}} = V_{\text{FB}}$, $V_{\text{SET}} = \text{Set Output Voltage}$, unless otherwise noted.

The specifications surrounded by are guaranteed by design engineering at $-40^\circ\text{C} \leq T_a \leq 125^\circ\text{C}$.

R1513SxxxB/D (-AE) Electrical Characteristics

($T_a = 25^\circ\text{C}$)

Symbol	Item	Conditions	Min.	Typ.	Max.	Unit
I_{SS}	Supply Current	$V_{\text{IN}} = 14 \text{ V}$, $I_{\text{OUT}} = 0 \text{ mA}$		75	110	μA
I_{standby}	Standby Current	$V_{\text{IN}} = 36 \text{ V}$, $V_{\text{CE}} = 0 \text{ V}$		0.1	2.0	μA
V_{OUT}	Output Voltage	$3.5 \text{ V} \leq V_{\text{SET}} + 1 \text{ V} \leq V_{\text{IN}} \leq 36 \text{ V}$, $I_{\text{OUT}} = 1 \text{ mA}$	$V_{\text{SET}} \leq 1.8 \text{ V}$		18	mV
			$1.8 \text{ V} < V_{\text{SET}}$		×1.01	V
		$3.5 \text{ V} \leq V_{\text{SET}} + 1 \text{ V} \leq V_{\text{IN}} \leq 14 \text{ V}$, $1 \text{ mA} \leq I_{\text{OUT}} \leq 50 \text{ mA}$	$V_{\text{SET}} \leq 1.8 \text{ V}$		18	mV
			$1.8 \text{ V} < V_{\text{SET}}$		×1.01	V
$\Delta V_{\text{OUT}} / \Delta V_{\text{IN}}$	Line Regulation	$3.5 \text{ V} \leq V_{\text{SET}} + 1 \text{ V} \leq V_{\text{IN}} \leq 36 \text{ V}$, $I_{\text{OUT}} = 1 \text{ mA}$	-0.02	0.01	0.02	%/V
$\Delta V_{\text{OUT}} / \Delta I_{\text{OUT}}$	Load Regulation	$3.5 \text{ V} \leq V_{\text{IN}} = V_{\text{SET}} + 1 \text{ V}$, $1 \text{ mA} \leq I_{\text{OUT}} \leq 300 \text{ mA}$	$V_{\text{SET}} \leq 1.8 \text{ V}$		5	mV
			$V_{\text{SET}} \leq 3.4 \text{ V}$		8	
			$V_{\text{SET}} \leq 5.0 \text{ V}$		12	
V_{DIF}	Dropout Voltage	$I_{\text{OUT}} = 300 \text{ mA}$	$V_{\text{SET}} = 1.2 \text{ V}$		2.30	V
			$1.5 \text{ V} \leq V_{\text{SET}}$		2.00	
			$1.8 \text{ V} \leq V_{\text{SET}}$		1.70	
			$3.3 \text{ V} \leq V_{\text{SET}}$	0.39	0.74	
			$5.0 \text{ V} \leq V_{\text{SET}}$	0.32	0.60	
I_{LIM}	Output Current Limit	$V_{\text{IN}} = V_{\text{SET}} + 1.5 \text{ V}$	300	450		mA
I_{SC}	Short Current Limit	$V_{\text{OUT}} = 0 \text{ V}$	40	50		mA
R_{FB}	Feedback Resistance		1.0	2.4		M Ω
V_{CEH}	CE Input Voltage "H"		2.2		36	V
V_{CEL}	CE Input Voltage "L"		0		1.0	V
I_{PD}	CE Pull-down Current	$V_{\text{CE}} = 5.0 \text{ V}$		0.2	0.6	μA
		$V_{\text{CE}} = 36 \text{ V}$		0.5	1.3	
T_{TSD}	Thermal Shutdown Temperature	Junction Temperature	150	160		$^\circ\text{C}$
T_{TSR}	Thermal Shutdown Released Temperature	Junction Temperature	125	135		$^\circ\text{C}$
R_{LOW}	Low Output Nch Tr. ON Resistance (R1513SxxxD)	$V_{\text{IN}} = 14.0 \text{ V}$, $V_{\text{CE}} = 0 \text{ V}$	1.5	3.2	6.7	k Ω

All test items listed under *Electrical Characteristics* are done under the pulse load condition ($T_j \approx T_a = 25^\circ\text{C}$).

The specifications surrounded by are guaranteed by design engineering at $-40^{\circ}\text{C} \leq T_a \leq 125^{\circ}\text{C}$.

Product-specific Electrical Characteristics (-AE)

($T_a = 25^{\circ}\text{C}$)

Product Name	V_{OUT} [V]			$\Delta V_{\text{OUT}}/\Delta I_{\text{OUT}}$ [mV]		V_{DIF} [V]	
	MIN.	TYP.	MAX.	MIN.	MAX.	TYP.	MAX.
R1513S121x	1.182	1.200	1.218	-5	5		2.30
R1513S151x	1.482	1.500	1.518	-5	5		2.00
R1513S181x	1.782	1.800	1.818	-5	5		1.70
R1513S331x	3.267	3.300	3.333	-8	8	0.39	0.74
R1513S341x	3.366	3.400	3.434	-8	8	0.39	0.74
R1513S401x	3.960	4.000	4.040	-12	12	0.39	0.74
R1513S501x	4.950	5.000	5.050	-12	12	0.32	0.60

C1 = 1.0 μ F, C2 = 4.7 μ F, $V_{OUT} = V_{FB}$, V_{SET} = Set Output Voltage, unless otherwise noted.

R1513SxxxB/D (-KE) Electrical Characteristics

(−40°C ≤ Ta ≤ 125°C)

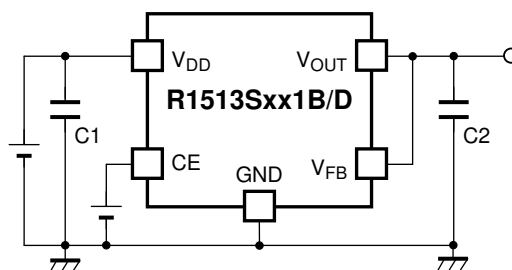
Symbol	Item	Conditions	Min.	Typ.	Max.	Unit
I _{SS}	Supply Current	V _{IN} = 14 V, I _{OUT} = 0 mA		75	110	μ A
I _{standby}	Standby Current	V _{IN} = 36 V, V _{CE} = 0 V		0.1	2.0	μ A
V _{OUT}	Output Voltage	3.5 V ≤ V _{SET} + 1 V ≤ V _{IN} ≤ 36 V, I _{OUT} = 1 mA	V _{SET} ≤ 1.8 V	−18	18	mV
			1.8 V < V _{SET}	×0.99	×1.01	V
		3.5 V ≤ V _{SET} + 1 V ≤ V _{IN} ≤ 14 V, 1 mA ≤ I _{OUT} ≤ 50 mA	V _{SET} ≤ 1.8 V	−18	18	mV
			1.8 V < V _{SET}	×0.99	×1.01	V
$\Delta V_{OUT} / \Delta V_{IN}$	Line Regulation	3.5 V ≤ V _{SET} + 1 V ≤ V _{IN} ≤ 36 V, I _{OUT} = 1 mA	−0.02	0.01	0.02	%/V
$\Delta V_{OUT} / \Delta I_{OUT}$	Load Regulation	3.5 V ≤ V _{IN} = V _{SET} + 1 V, 1 mA ≤ I _{OUT} ≤ 300 mA	V _{SET} ≤ 1.8 V	−5	5	mV
			V _{SET} ≤ 3.4 V	−8	8	
			V _{SET} ≤ 5.0 V	−12	12	
V _{DIF}	Dropout Voltage	I _{OUT} = 300 mA	V _{SET} = 1.2 V		2.30	V
			1.5V ≤ V _{SET}		2.00	
			1.8V ≤ V _{SET}		1.70	
			3.3V ≤ V _{SET}	0.39	0.74	
			5.0V ≤ V _{SET}	0.32	0.60	
I _{LIM}	Output Current Limit	V _{IN} = V _{SET} + 1.5 V	300	450		mA
I _{SC}	Short Current Limit	V _{OUT} = 0 V	40	50		mA
R _{FB}	Feedback Resistance		1.0	2.4		M Ω
V _{CEH}	CE Input Voltage "H"		2.2		36	V
V _{CEL}	CE Input Voltage "L"		0		1.0	V
I _{PD}	CE Pull-down Current	V _{CE} = 5.0 V		0.2	0.6	μ A
		V _{CE} = 36 V		0.5	1.3	
T _{TSD}	Thermal Shutdown Temperature	Junction Temperature	150	160		°C
T _{TSR}	Thermal Shutdown Released Temperature	Junction Temperature	125	135		°C
R _{LOW}	Low Output Nch Tr. ON Resistance (R1513SxxxD)	V _{IN} = 14.0 V, V _{CE} = 0 V	1.5	3.2	6.7	k Ω

Product-specific Electrical Characteristics (-KE)

(-40°C ≤ Ta ≤ 125°C)

Product Name	V _{OUT} [V]			Δ V _{OUT} /Δ I _{OUT} [mV]		V _{DIF} [V]	
	MIN.	TYP.	MAX.	MIN.	MAX.	TYP.	MAX.
R1513S121x	1.182	1.200	1.218	-5	5		2.30
R1513S151x	1.482	1.500	1.518	-5	5		2.00
R1513S181x	1.782	1.800	1.818	-5	5		1.70
R1513S331x	3.267	3.300	3.333	-8	8	0.39	0.74
R1513S341x	3.366	3.400	3.434	-8	8	0.39	0.74
R1513S401x	3.960	4.000	4.040	-12	12	0.39	0.74
R1513S501x	4.950	5.000	5.050	-12	12	0.32	0.60

TYPICAL APPLICATION



R1513S Typical Application

External Components List

Symbol	Description
C1	1.0 μ F, Ceramic Capacitor
C2	4.7 μ F, Ceramic Capacitor

TECHNICAL NOTES

Phase Compensation

Phase compensation is provided to secure stable operation even when the load current is varied. For this purpose, use a 4.7 μ F or more output capacitor (C2) with good frequency characteristics and proper ESR (Equivalent Series Resistance). Connect a 1.0 μ F or more input capacitor (C1) between the V_{DD} pin and the GND pin as close as possible to the pins.

In case of using a tantalum type capacitor with a large ESR, the output might become unstable. Evaluate your circuit including consideration of frequency characteristics.

Depending on the capacitor size, manufacturer, and part number, the bias characteristics and the temperature characteristics vary.

PCB Layout

Ensure the V_{DD} and GND lines are sufficiently robust. If their impedance is too high, noise pickup or unstable operation may result. No. 2 pin and No.5 pin must be wired together when mounting on board. Connect a capacitor with a suitable value between the V_{DD} and GND pins, and as close as possible to the pins. The load regulation can be improved by short-circuiting V_{OUT} and V_{FB} close to the load device.

Thermal Shutdown Function

Thermal shutdown function detects overheating of the regulator and stops the regulator operation to protect the device from damage. Thermal shutdown circuit stops the regulator operation if the junction temperature becomes higher than 160°C (Typ.) and restarts the regulator operation if the junction temperature drops below 135°C (Typ.). The regulator repeats turning on and off and creates pulse waveform until the cause of the overheating is removed.

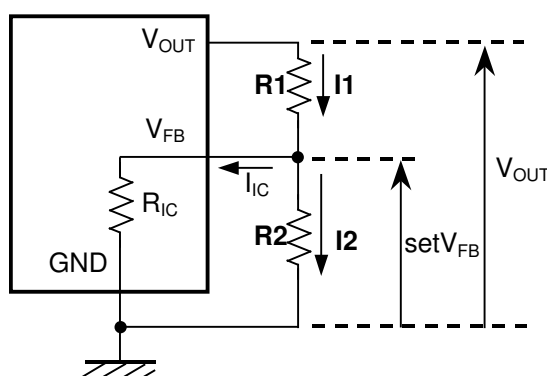
Adjustable Output Voltage Setting

Output voltage can be adjusted by using the external divider resistors (R1, R2). By using the following equation, the output voltage (V_{OUT}) can be determined. The voltage which is fixed inside the IC is described as V_{FB} .

$$V_{OUT} = V_{FB} \times ((R1 + R2) / R2)$$

Recommended Output Voltage Range: $1.2 \text{ V} \leq V_{OUT} \leq 18 \text{ V}$

$$V_{FB} = V_{SET}$$

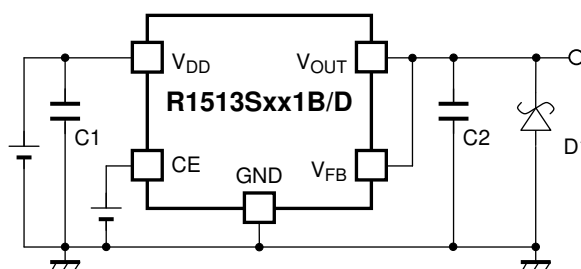


Output Voltage Adjustment Using External Divider Resistors (R1, R2)

The minimum resistance value for a resistor (R_{IC}) is 1 M Ω ($T_a = 25^\circ\text{C}$, guaranteed by design). For better accuracy, setting $R1 \ll R_{IC}$ reduces errors. The resistance value for a resistor ($R2$) should be set to 33 k Ω or lower. If the resistance values set for $R1$ and $R2$ are larger, the impedance of the V_{FB} pin becomes larger.

R_{IC} could be affected by temperature; therefore, evaluate the circuit taking the actual conditions of use into account when deciding the resistance values for $R1$ and $R2$.

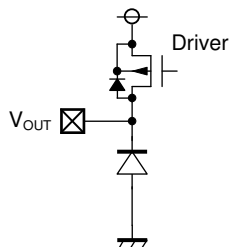
TYPICAL APPLICATION FOR IC CHIP BREAKDOWN PREVENTION



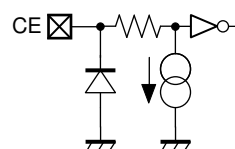
R1513S Typical Application for IC Chip Breakdown Prevention

When a sudden surge of electrical current travels along the V_{OUT} pin and GND due to a short-circuit, electrical resonance of a circuit involving an output capacitor ($C2$) and a short circuit inductor generates a negative voltage and may damage the device or the load devices. Connecting a schottky diode ($D1$) between the V_{OUT} pin and GND has the effect of preventing damage to them.

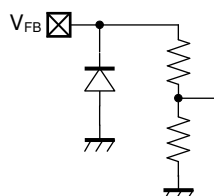
PIN EQUIVALENT CIRCUIT DIAGRAMS



V_{OUT} Pin Equivalent Circuit Diagrams



CE Pin Equivalent Circuit Diagrams



V_{FB} Pin Equivalent Circuit Diagrams

PACKAGE INFORMATION

POWER DISSIPATION (HSOP-6J)

The power dissipation of the package is dependent on PCB material, layout, and environmental conditions. The following conditions are used in this measurement.

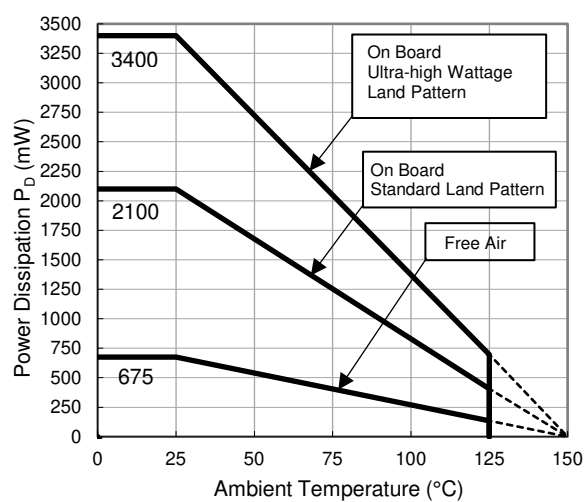
Measurement Conditions

	Ultra-high Wattage Land Pattern	Standard Land Pattern
Environment	Mounting on Board (Wind Velocity = 0 m/s)	Mounting on Board (Wind Velocity = 0 m/s)
Board Material	Glass Cloth Epoxy Plastic (Four-layer Board)	Glass Cloth Epoxy Plastic (Double-sided Board)
Board Dimensions	76.2 mm × 114.3 mm × 0.8 mm	50 mm × 50 mm × 1.6 mm
Copper Ratio	96%	50%
Through-holes	φ 0.3 mm × 28 pcs	φ 0.5 mm × 24 pcs

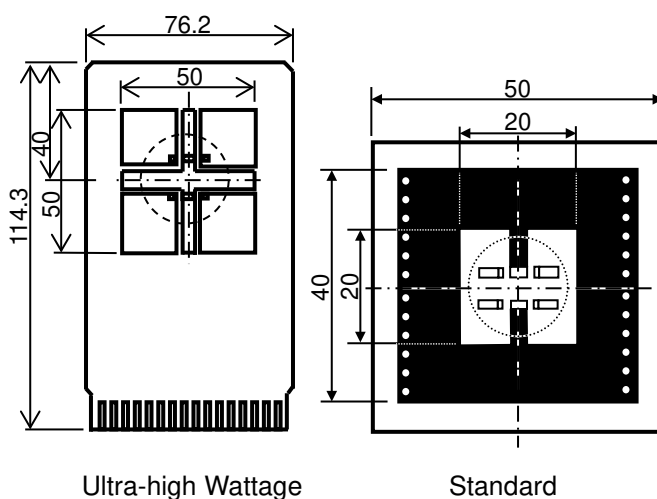
Measurement Result

(Ta = 25°C, Tjmax = 150°C)

	Ultra-high Wattage Land Pattern	Standard Land Pattern	Free Air
Power Dissipation	3400 mW	2100 mW	675 mW
Thermal Resistance	37°C/W	59°C/W	185°C/W



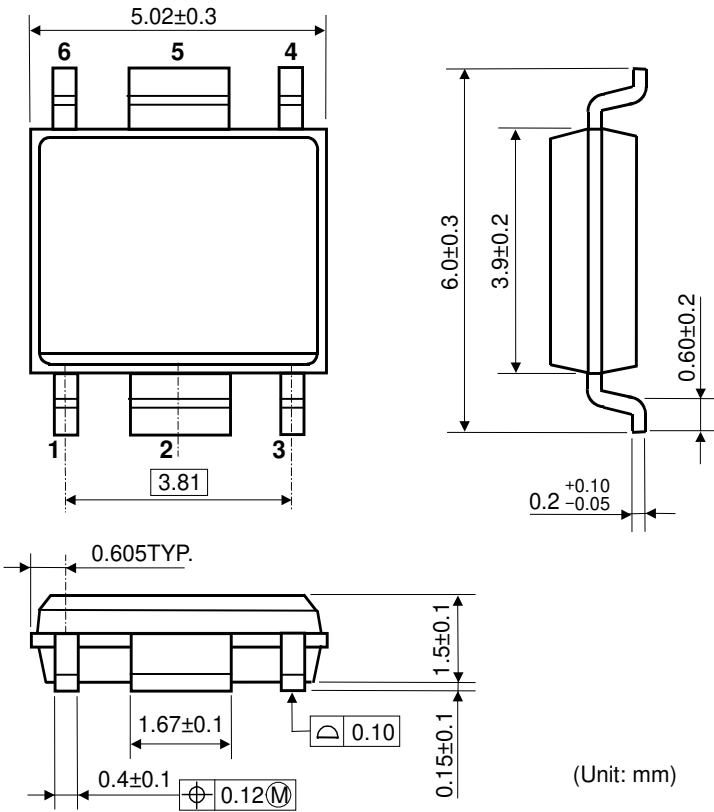
Power Dissipation vs. Ambient Temperature



○ IC Mount Area (mm)

Measurement Board Pattern

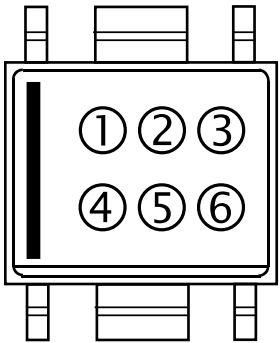
PACKAGE DIMENSIONS (HSOP-6J)



HSOP-6J Package Dimensions

MARK SPECIFICATION (HSOP-6J)

- ①②③④: Product Code ... **Refer to MARK SPECIFICATION TABLE (HSOP-6J).**
⑤⑥: Lot Number ... Alphanumeric Serial Number



HSOP-6J Mark Specification

MARK SPECIFICATION TABLE (HSOP-6J)**Mark Specification Table**

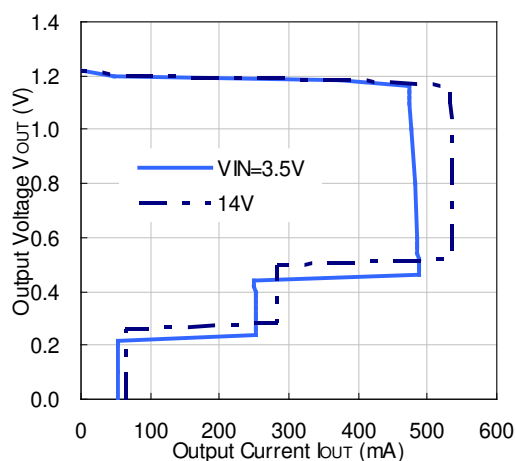
Product Name	①②③④
R1513S121B	Z 1 2 B
R1513S151B	Z 1 5 B
R1513S181B	Z 1 8 B
R1513S331B	Z 3 3 B
R1513S341B	Z 3 4 B
R1513S401B	Z 4 0 B
R1513S501B	Z 5 0 B
R1513S121D	Z 1 2 D
R1513S151D	Z 1 5 D
R1513S181D	Z 1 8 D
R1513S331D	Z 3 3 D
R1513S341D	Z 3 4 D
R1513S401D	Z 4 0 D
R1513S501D	Z 5 0 D

TYPICAL CHARACTERISTICS

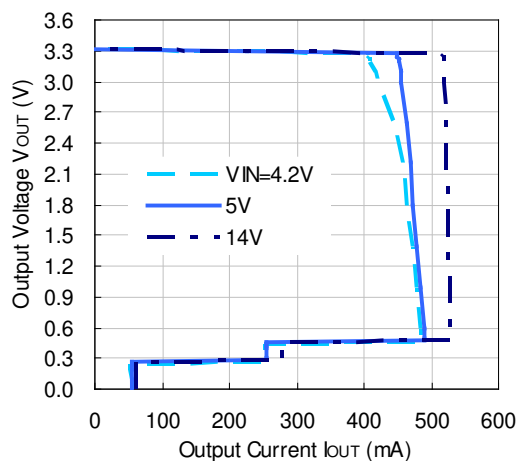
Note: Typical Characteristics are intended to be used as reference data; they are not guaranteed.

1) Output Voltage vs. Output Current ($T_a = 25^\circ\text{C}$)

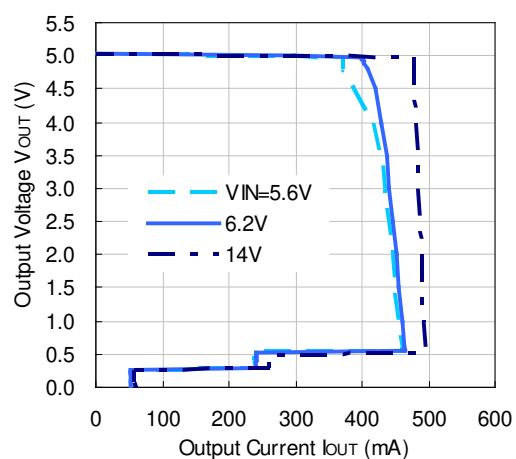
R1513S121B/D



R1513S331B/D

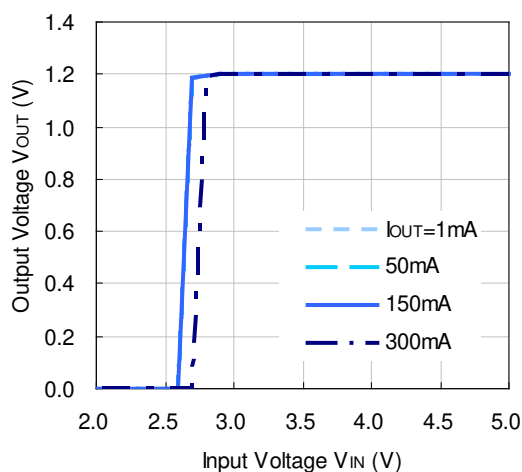


R1513S501B/D

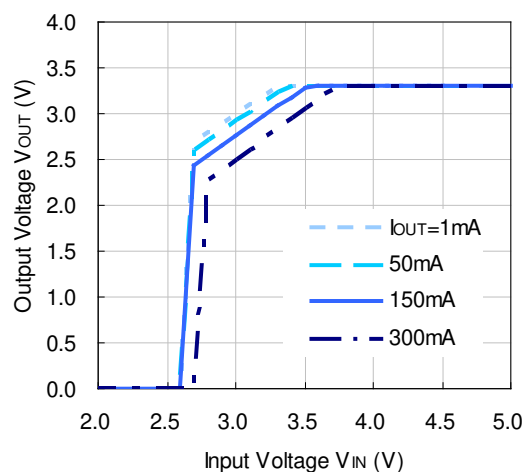


2) Output Voltage vs. Input Voltage ($T_a = 25^\circ\text{C}$)

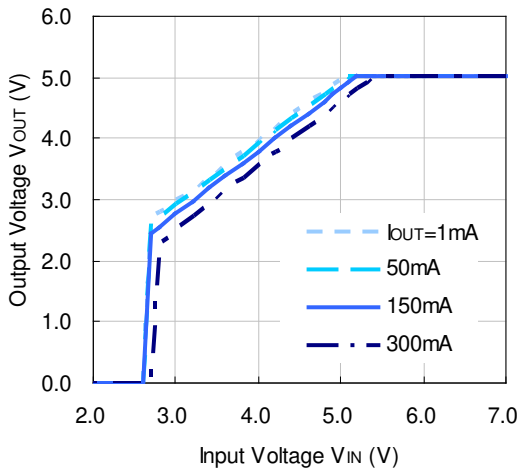
R1513S121B/D



R1513S331B/D

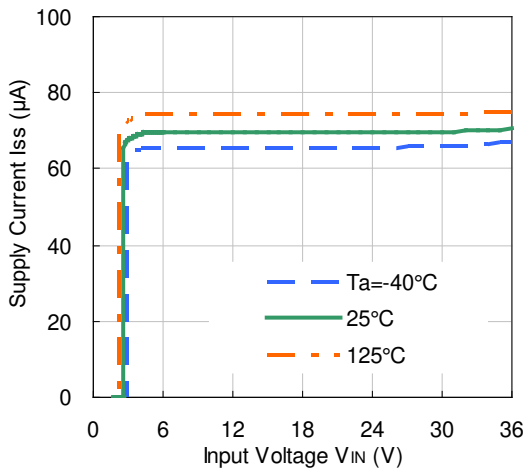


R1513S501B/D

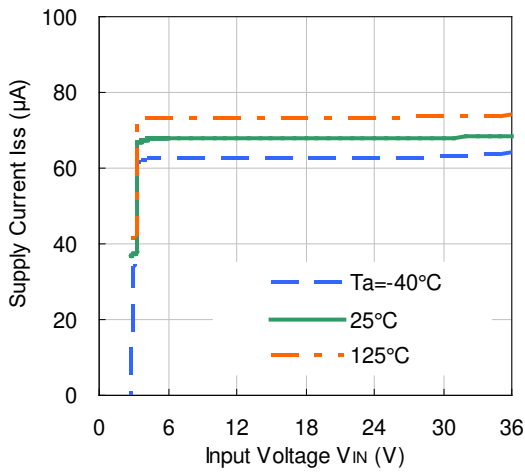


3) Supply Current vs. Input Voltage ($T_a = 25^\circ\text{C}$)

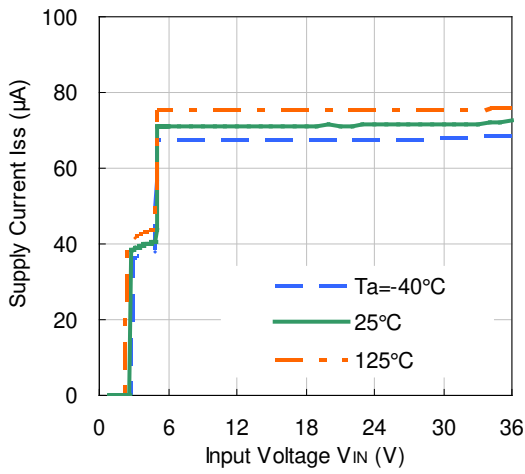
R1513S121B/D



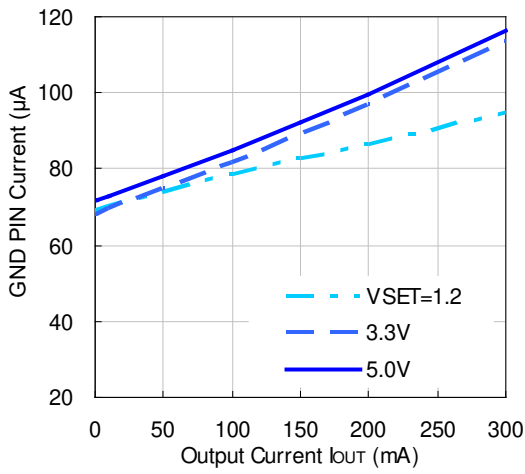
R1513S331B/D



R1513S501B/D

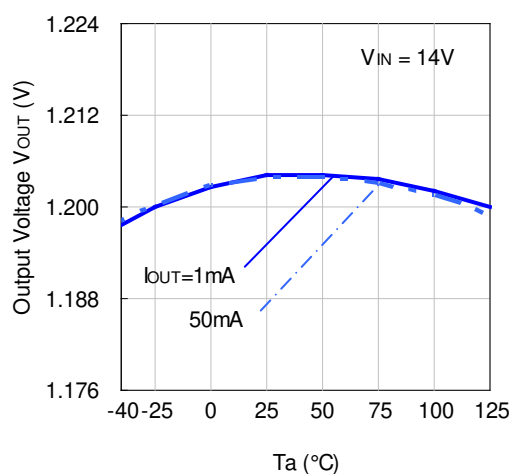


4) GND Pin Current vs. Output Current ($T_a = 25^\circ\text{C}$)

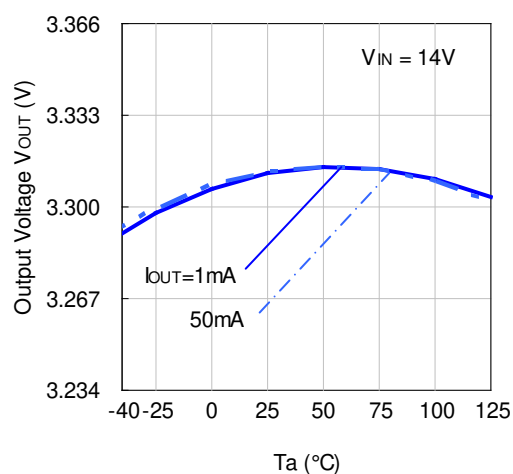


5) Output Voltage vs. Ambient Temperature

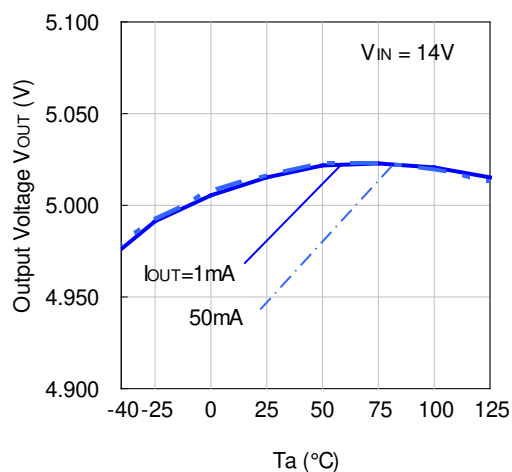
R1513S121B/D



R1513S331B/D

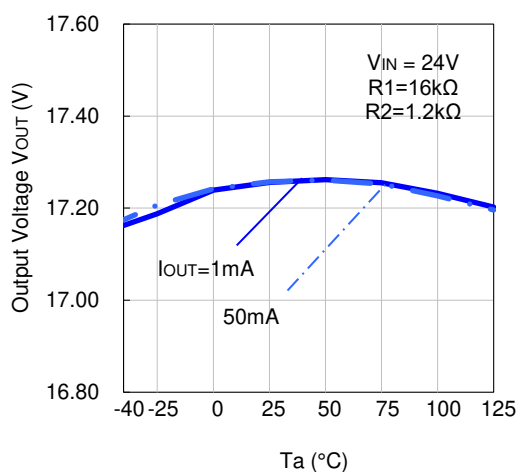


R1513S501B/D



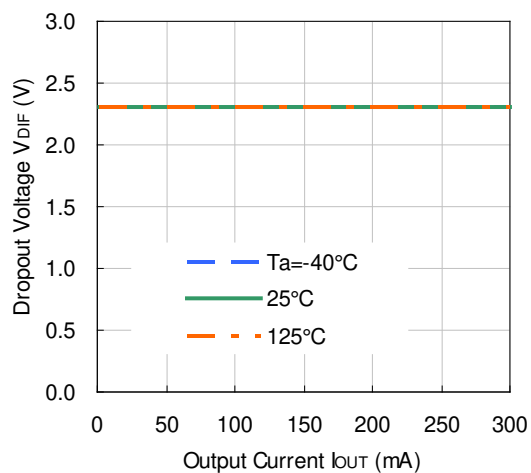
R1513S121B/D

(Output Voltage Adjusted to 17.2 V)

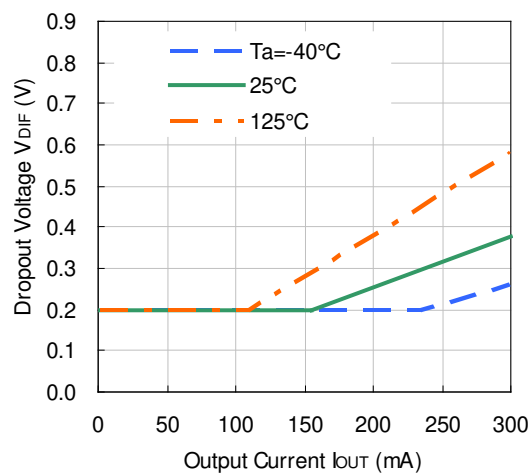


6) Dropout Voltage vs. Output Current

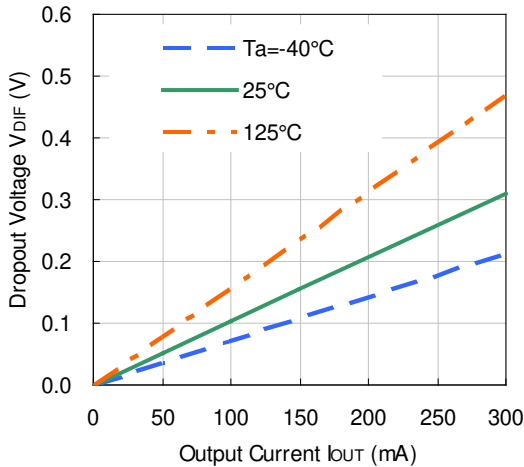
R1513S121B/D



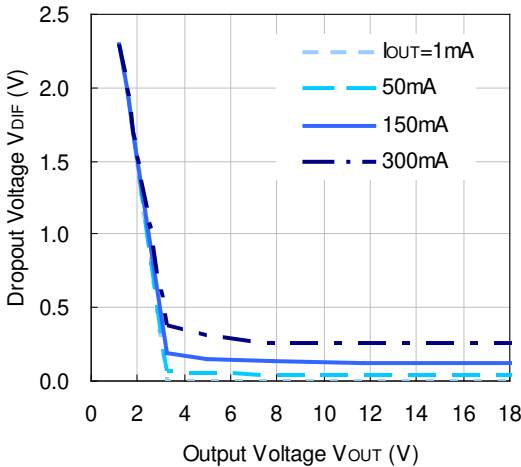
R1513S331B/D



R1513S501B/D

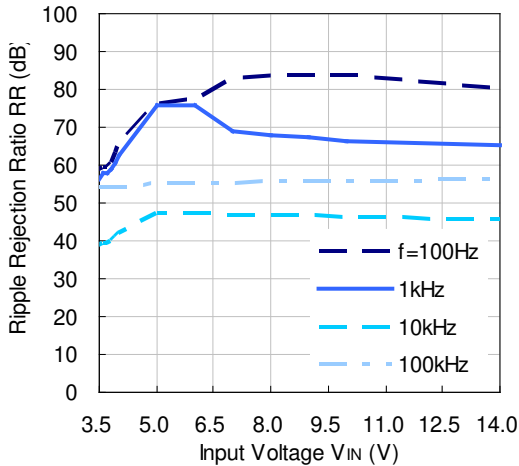


7) Dropout Voltage vs. Output Voltage ($T_a = 25^\circ\text{C}$)

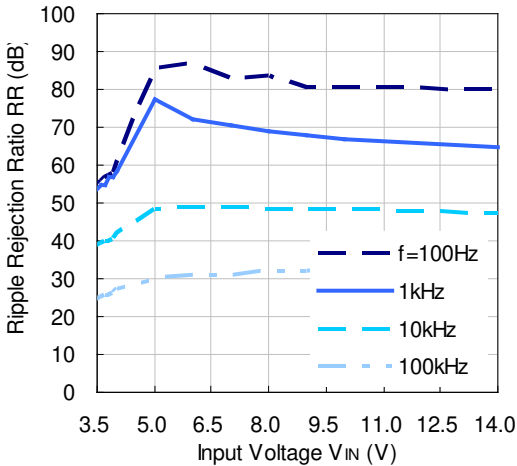


8) Ripple Rejection vs. Input Voltage ($T_a = 25^\circ\text{C}$, Ripple = 0.5 Vpp)

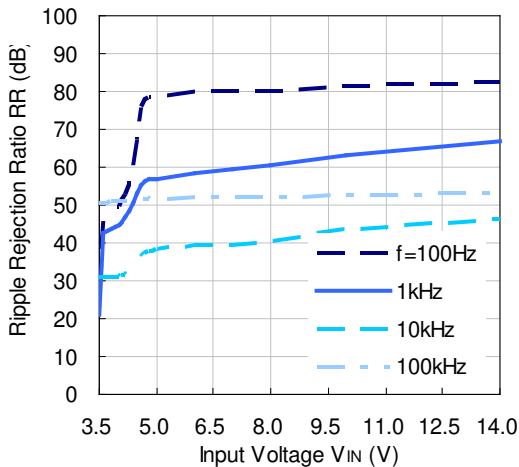
R1513S121B/D ($I_{OUT} = 1\text{ mA}$)



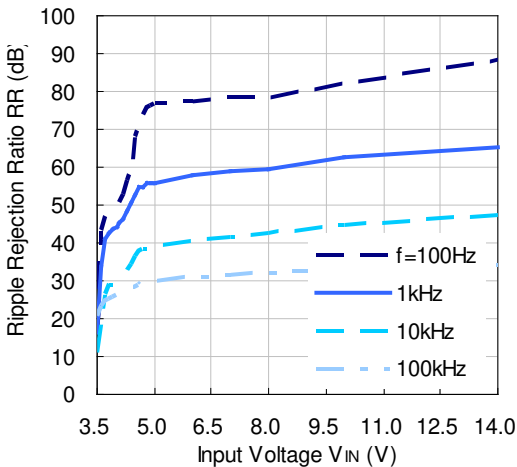
R1513S121B/D ($I_{OUT} = 50\text{ mA}$)

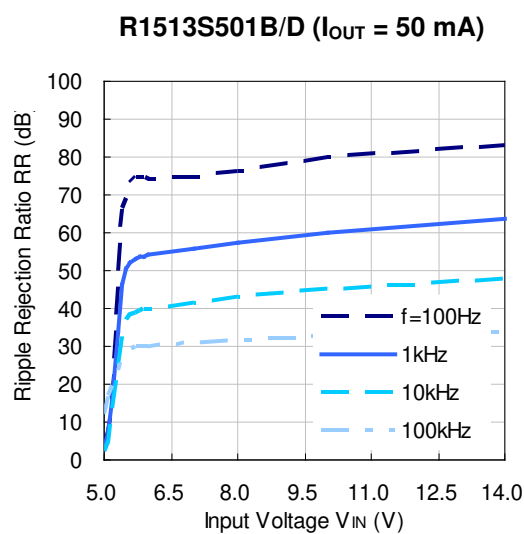
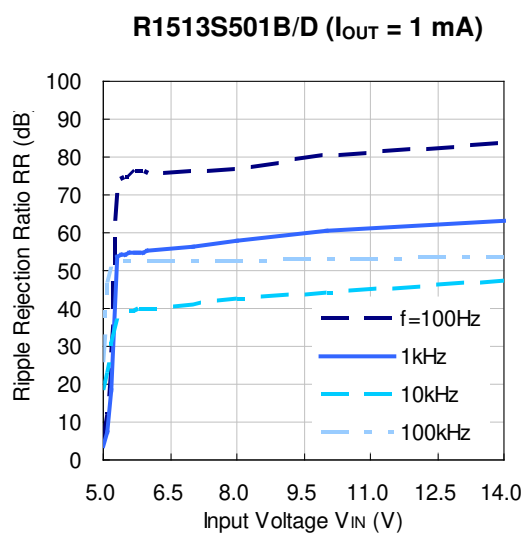


R1513S331B/D ($I_{OUT} = 1\text{ mA}$)

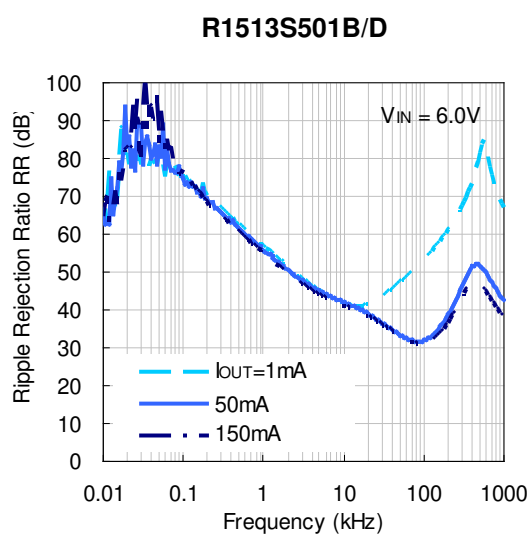
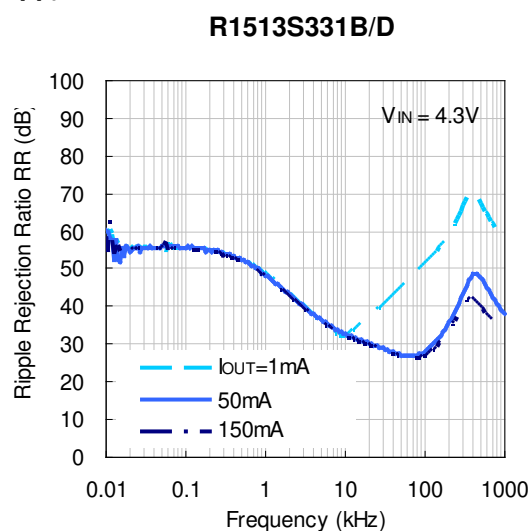
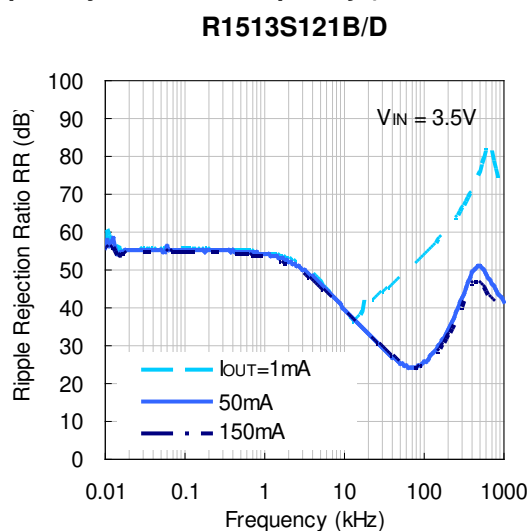


R1513S331B/D ($I_{OUT} = 50\text{ mA}$)



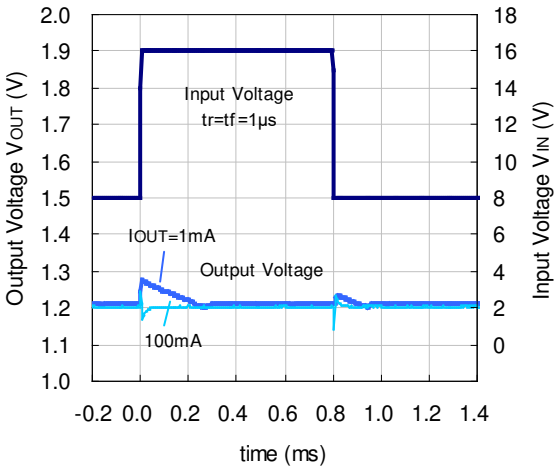


9) Ripple Rejection vs. Frequency ($T_a = 25^\circ\text{C}$, Ripple = 0.5 Vpp)

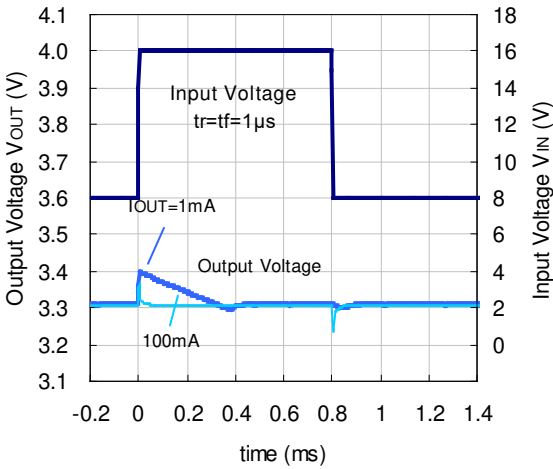


10) Input Transient Response ($T_a = 25^\circ\text{C}$, $C_2 = 4.7\mu\text{F}$)

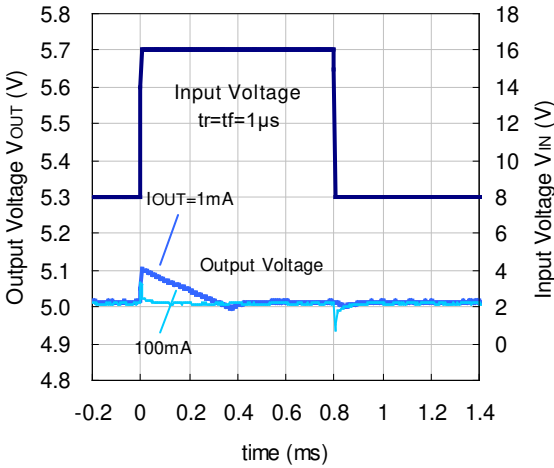
R1513S121B/D



R1513S331B/D

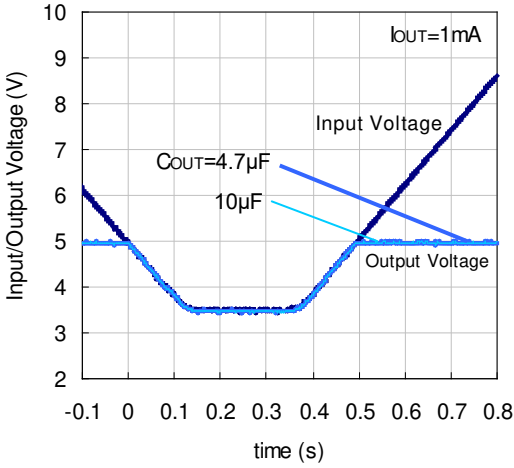


R1513S501B/D



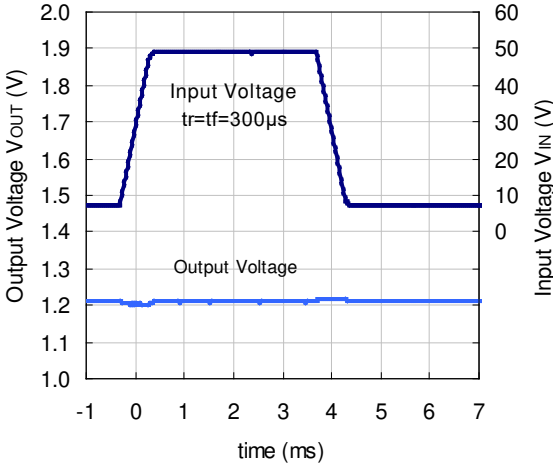
11) Cranking ($T_a = -18^\circ\text{C}$)

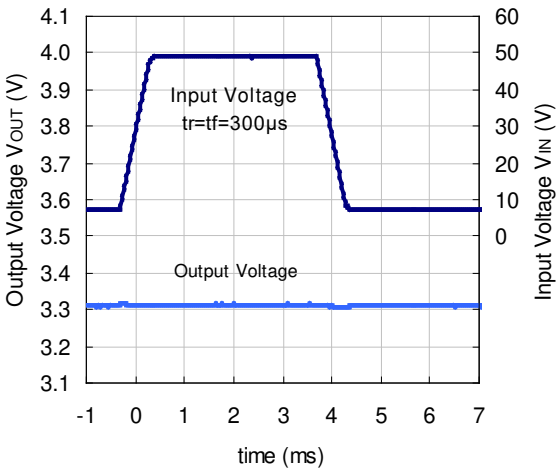
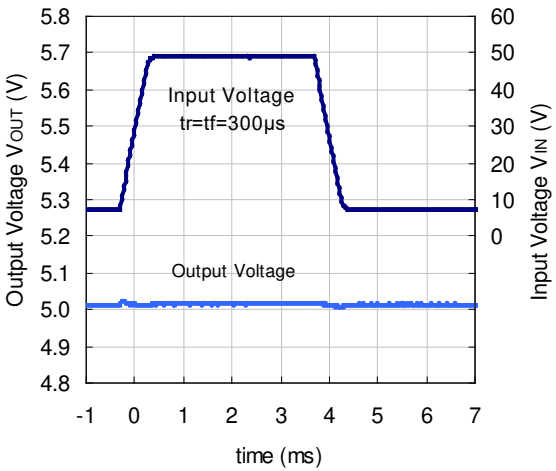
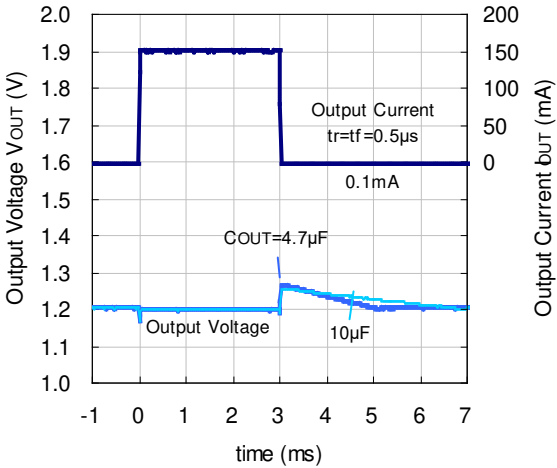
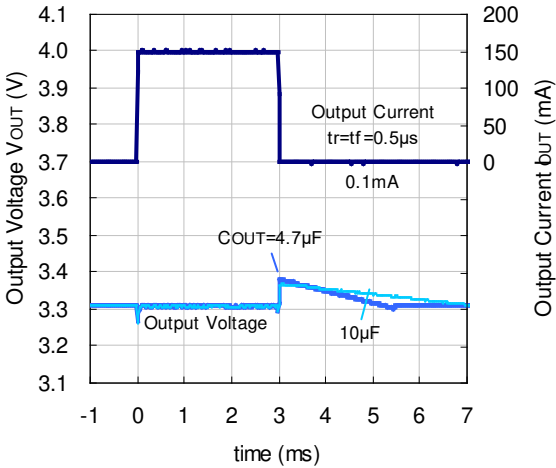
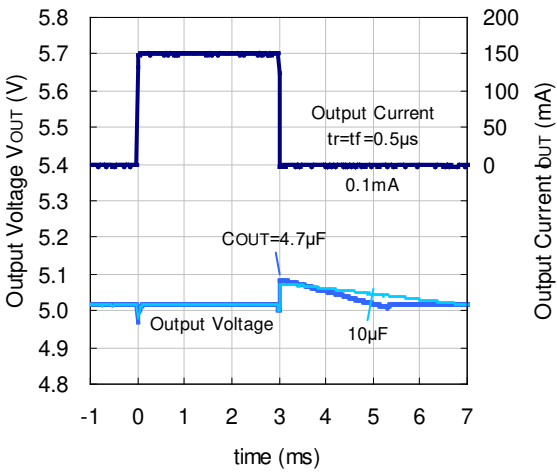
R1513S501B/D

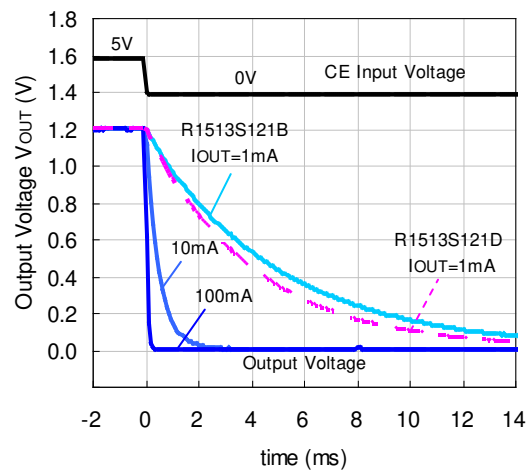
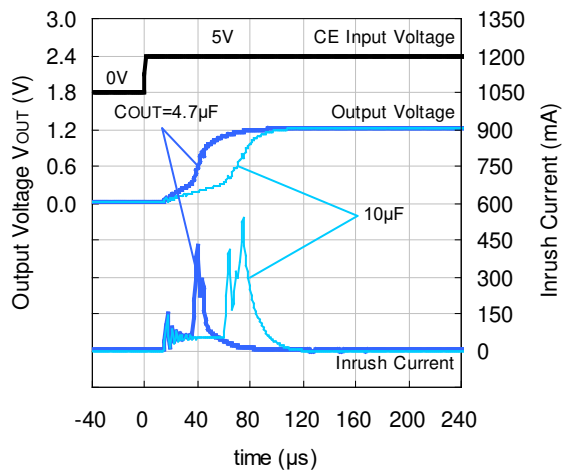
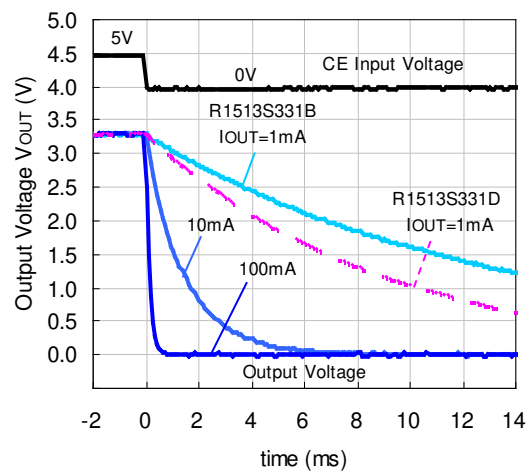
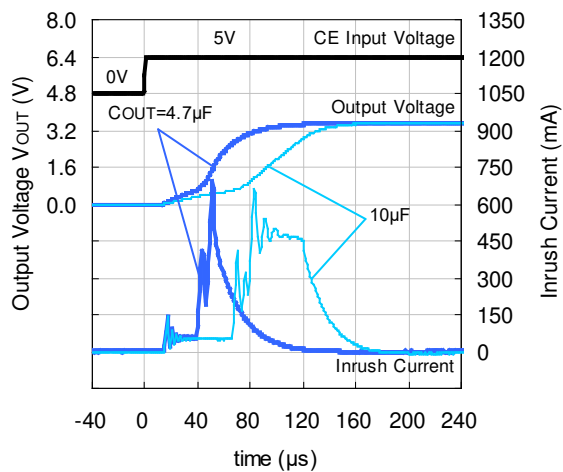
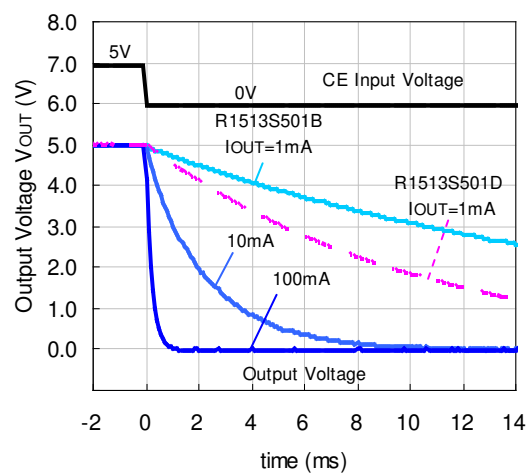
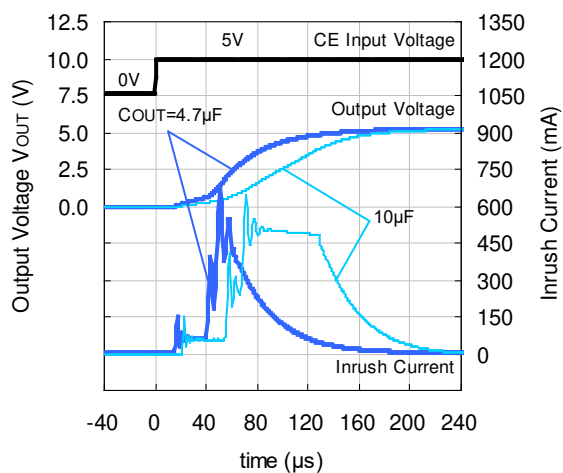


12) Load Dumping ($T_a = 25^\circ\text{C}$, $C_2 = 4.7\mu\text{F}$)

R1513S121B/D

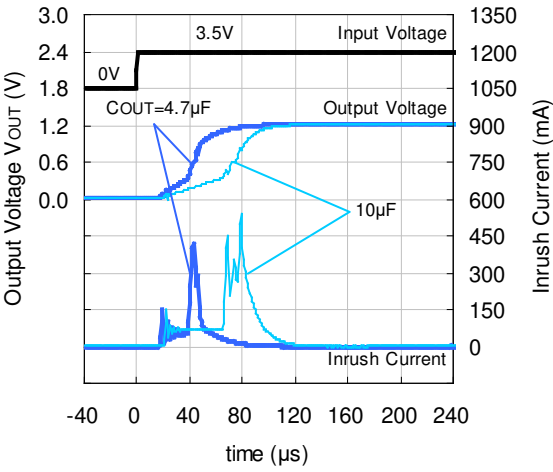


R1513S331B/D**R1513S501B/D****13) Load Transient Response ($T_a = 25^\circ C$)****R1513S121B/D****R1513S331B/D****R1513S501B/D**

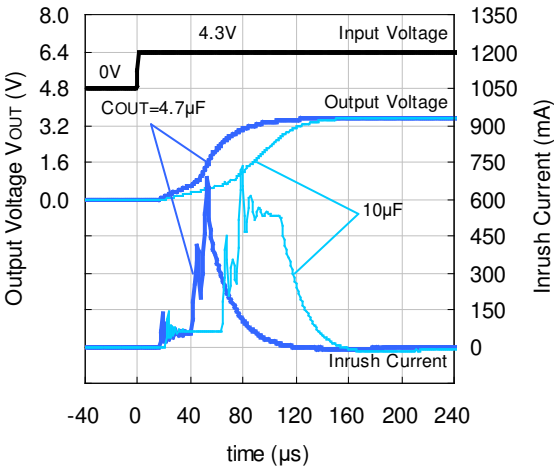
14) CE Transient Response ($T_a = 25^\circ\text{C}$)R1513S121B/D ($V_{IN} = 3.5\text{ V}$)R1513S331B/D ($V_{IN} = 4.3\text{ V}$)R1513S501B/D ($V_{IN} = 6.0\text{ V}$)

15) Power-on Transient Response ($T_a = 25^\circ\text{C}$, $V_{CE} = 5\text{ V}$)

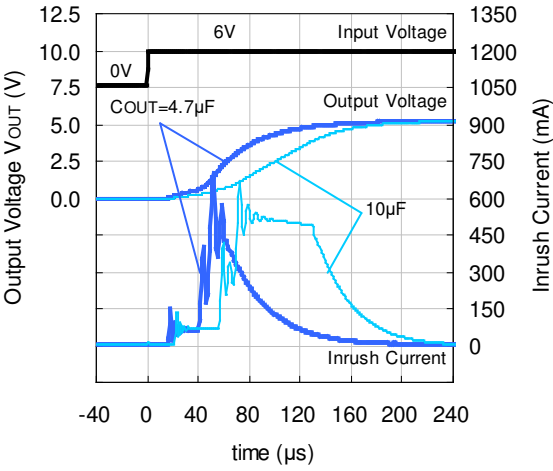
R1513S121B/D



R1513S331B/D

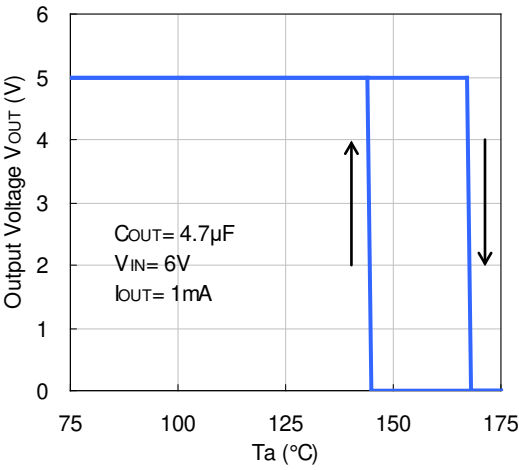


R1513S501B/D



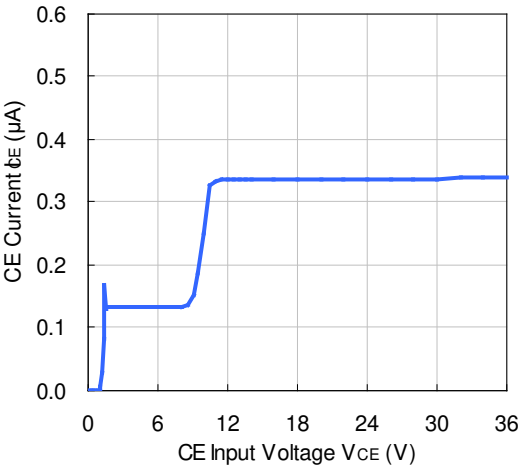
16) Thermal Shutdown

R1513S501B/D



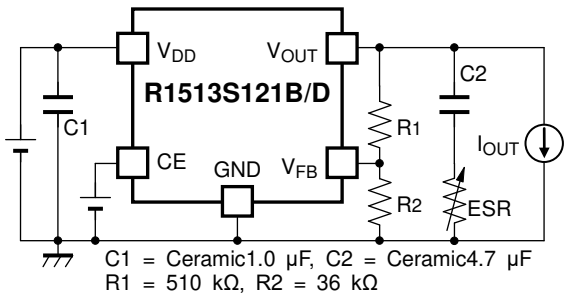
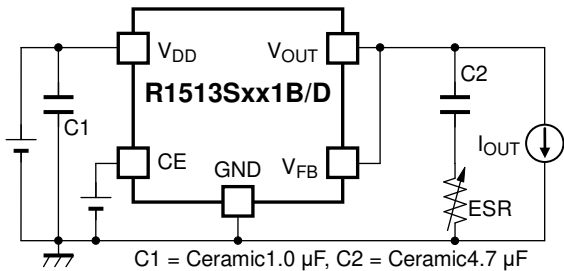
17) CE Pin Current vs. CE Pin Voltage ($T_a = 25^\circ\text{C}$)

R1513Sxx1B/D



Equivalent Series Resistance (ESR) vs. Output Current

It is recommended that a ceramic type capacitor be used for this device. However, other types of capacitors having lower ESR can also be used. The relation between the output current (I_{OUT}) and the ESR of output capacitor is shown below.



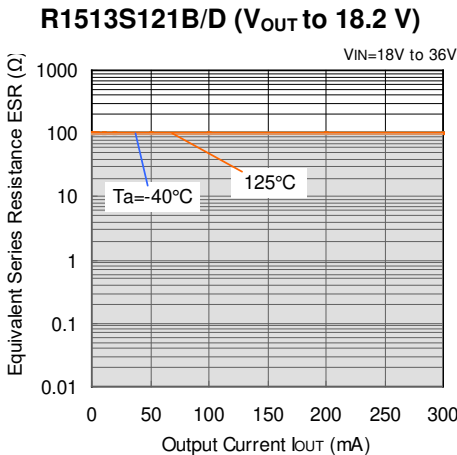
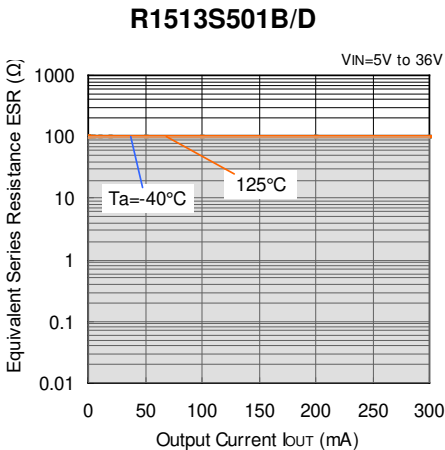
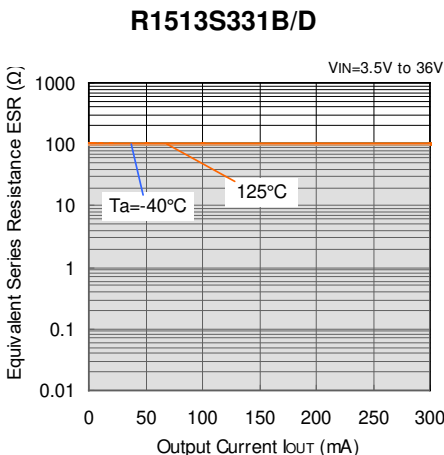
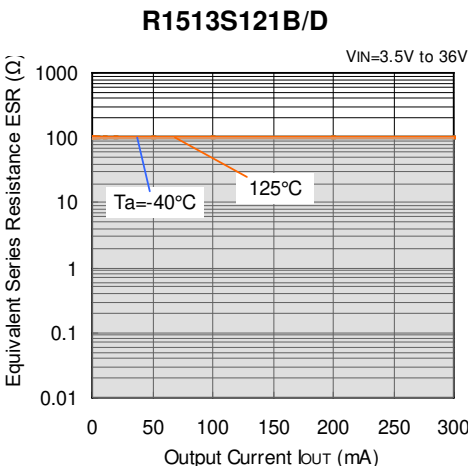
Measurement Conditions

Frequency Band: 10 Hz to 2 MHz

Ambient Temperature: -40°C to 125°C

Hatched Area: Noise level below 40 μ V (average)

Capacitor: C1 = 1.0 μ F Ceramic Capacitor, C2 = 4.7 μ F Ceramic Capacitor (CGA4J3X7R1C475K125AB)



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 - Traffic control system
 - Combustion equipment

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8. Quality Warranty
 - 8-1. Quality Warranty Period

In the case of a product purchased through an authorized distributor or directly from us, the warranty period for this product shall be one (1) year after delivery to your company. For defective products that occurred during this period, we will take the quality warranty measures described in section 8-2. However, if there is an agreement on the warranty period in the basic transaction agreement, quality assurance agreement, delivery specifications, etc., it shall be followed.
 - 8-2. Quality Warranty Remedies

When it has been proved defective due to manufacturing factors as a result of defect analysis by us, we will either deliver a substitute for the defective product or refund the purchase price of the defective product.

Note that such delivery or refund is sole and exclusive remedies to your company for the defective product.
 - 8-3. Remedies after Quality Warranty Period

With respect to any defect of this product found after the quality warranty period, the defect will be analyzed by us. On the basis of the defect analysis results, the scope and amounts of damage shall be determined by mutual agreement of both parties. Then we will deal with upper limit in Section 8-2. This provision is not intended to limit any legal rights of your company.
9. Anti-radiation design is not implemented in the products described in this document.
10. The X-ray exposure can influence functions and characteristics of the products. Confirm the product functions and characteristics in the evaluation stage.
11. WLCSP products should be used in light shielded environments. The light exposure can influence functions and characteristics of the products under operation or storage.
12. Warning for handling Gallium and Arsenic (GaAs) products (Applying to GaAs MMIC, Photo Reflector). These products use Gallium (Ga) and Arsenic (As) which are specified as poisonous chemicals by law. For the prevention of a hazard, do not burn, destroy, or process chemically to make them as gas or power. When the product is disposed of, please follow the related regulation and do not mix this with general industrial waste or household waste.
13. Please contact our sales representatives should you have any questions or comments concerning the products or the technical information.



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